NSN 5961-01-227-9211

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View Online at https://aerobasegroup.com/nsn/5961-01-227-9211 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.200 inches **Overall Diameter:** 0.370 inches **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Terminal Circle Diameter:** 0.210 inches **Criticality Code Justification: Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 300.0 breakdown voltage, dc all semiconductor device diode and 1.2 forward voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 50.00 microamperes forward current, average peak all semiconductor device diode **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Weapons system essential **Precious Material And Location:** Terminals external surfaces gold **Precious Material:** Gold **Test Data Document:** 80063-a3012736 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Yes - demil/mli

Demilitarization:

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